



TS13003

High Voltage NPN Transistor

TO-126



1 2 3

TO-92



1 2 3

Pin assignment:

TO-92

1. Emitter
2. Collector
3. Base

TO-126

1. Base
2. Collector
3. Emitter

$$BV_{CEO} = 400V$$

$$BV_{CBO} = 700V$$

$$I_C = 1.5A$$

$$V_{CE(SAT)} = 0.8V @ I_C / I_B = 0.5A / 0.1A$$

Features

- ◇ High voltage.
- ◇ High speed switching

Structure

- ◇ Silicon triple diffused type.
- ◇ NPN silicon transistor

Ordering Information

Part No.	Packing	Package
TS13003CT	Bulk	TO-92
TS13003CK		TO-126

Absolute Maximum Rating (Ta = 25 °C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V_{CBO}	700V	V
Collector-Emitter Voltage	V_{CEO}	400V	V
Emitter-Base Voltage	V_{EBO}	9	V
Collector Current	DC	1.5	A
	Pulse	3	
Collector Power Dissipation	TO-92	0.6	W
	TO-126	20	
Operating Junction Temperature	T_J	+150	°C
Operating Junction and Storage Temperature Range	T_{STG}	- 55 to +150	°C

Electrical Characteristics (Ta = 25 °C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Static						
Collector-Base Voltage	$I_C = 10mA, I_B = 0$	BV_{CBO}	700	--	--	V
Collector-Emitter Breakdown Voltage	$I_C = 10mA, I_E = 0$	BV_{CEO}	400	--	--	V
Emitter-Base Breakdown Voltage	$I_E = 1mA, I_C = 0$	BV_{EBO}	9	--	--	V
Collector Cutoff Current	$V_{CB} = 700V, I_E = 0$	I_{CBO}	--	--	100	uA
Emitter Cutoff Current	$V_{EB} = 9V, I_C = 0$	I_{EBO}	--	--	10	uA
Collector-Emitter Saturation Voltage	$I_C / I_B = 1.5A / 0.5A$	$V_{CE(SAT)1}$	--	--	3	V
	$I_C / I_B = 0.5A / 0.1A$	$V_{CE(SAT)2}$	--	--	0.8	
DC Current Gain	$V_{CE} = 10V, I_C = 0.4A$	h_{FE}	20	--	40	
	$V_{CE} = 2V, I_C = 1.0A$		8	--	40	
	$V_{CE} = 5V, I_C = 10uA$		6	--	40	
Frequency	$V_{CE} = 10V, I_C = 0.1A$	f_T	4	--	--	MHz
Output Capacitance	$V_{CB} = 10V, f = 0.1MHz$	C_{ob}	--	21	--	pF
Turn On Time	$V_{CC} = 125V, I_C = 1A,$	t_{ON}	--	1.1	--	uS
Storage Time	$I_{B1} = 0.2A, I_{B2} = - 0.2A,$	t_{STG}	--	--	4	uS
Fall Time	$R_L = 125ohm$	t_f	--	--	0.7	uS

Note : pulse test: pulse width $\leq 5mS$, duty cycle $\leq 10\%$

Electrical Characteristics Curve

Figure 1. Static Characteric

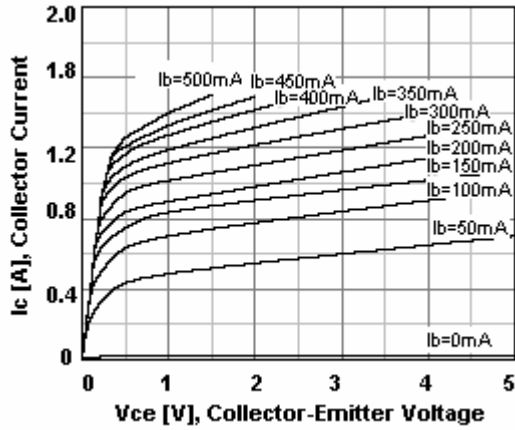


Figure 2. DC Current Gain

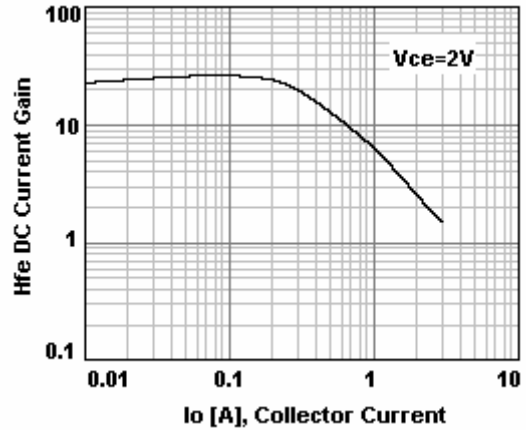


Figure 3. Vce(sat) v.s. Vbe(sat)

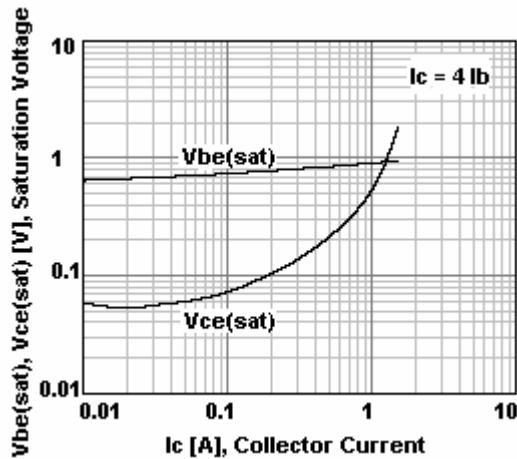


Figure 4. Switching Time

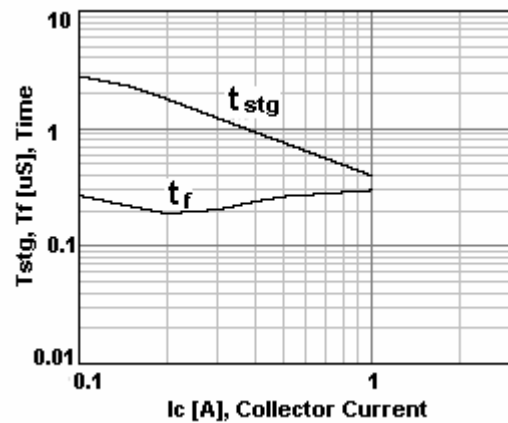


Figure 5. Safe Operating Area

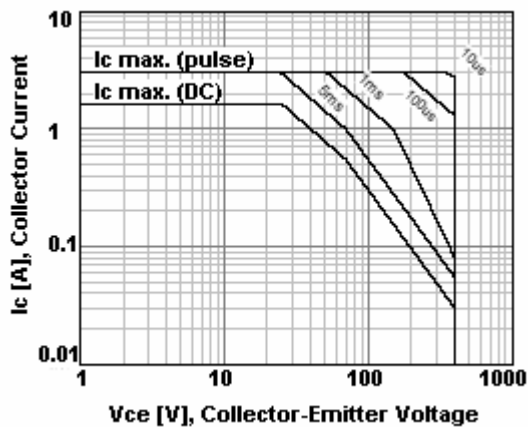
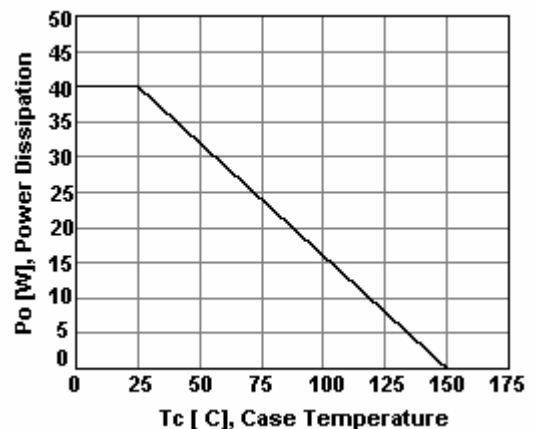
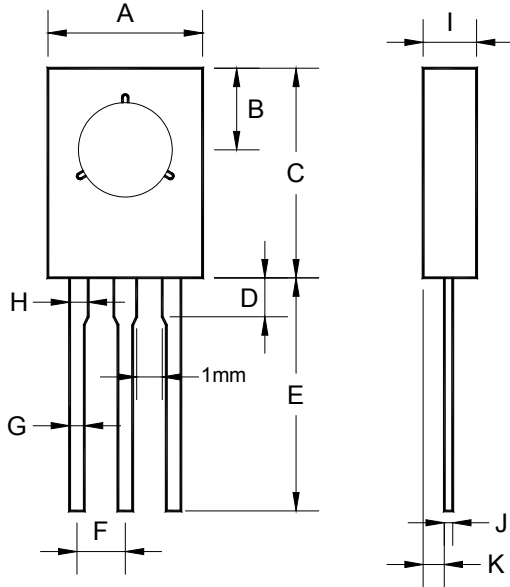


Figure 6. Power Derating

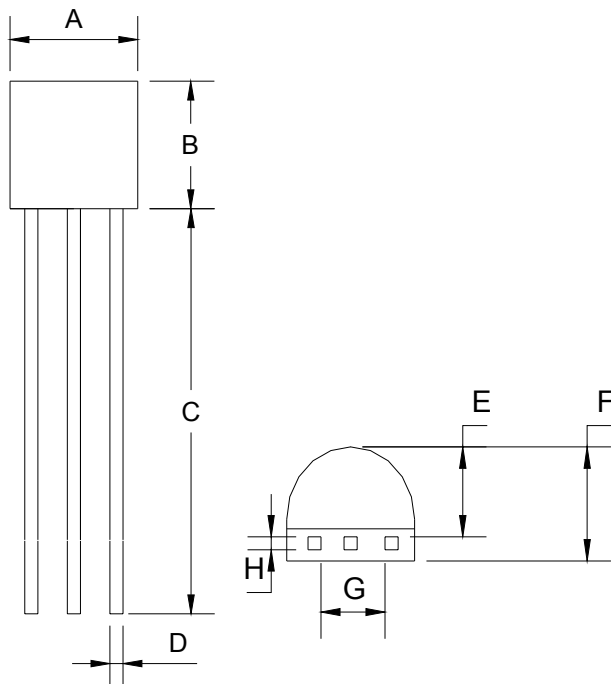


TO-126 Mechanical Drawing



TO-126 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	8.00 (typ)		0.315(typ)	
B	4.20 (typ)		0.165 (typ)	
C	10.58	11.00	0.417	0.433
D	2.00 (typ)		0.079 (typ)	
E	12.00(typ)		0.472(typ)	
F	2.50(typ)		0.098 (typ)	
G	0.74	0.78	0.029	0.031
H	0.8 (typ)		0.031(typ)	
I	2.56	3.00	0.101	0.118
J	0.38	0.50	0.015	0.020
K	1.1 (typ)		0.043 (typ)	

TO-92 Mechanical Drawing



TO-92 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.30	4.70	0.169	0.185
B	4.30	4.70	0.169	0.185
C	14.30(typ)		0.563(typ)	
D	0.43	0.49	0.017	0.019
E	2.19	2.81	0.086	0.111
F	3.30	3.70	0.130	0.146
G	2.42	2.66	0.095	0.105
H	0.37	0.43	0.015	0.017